

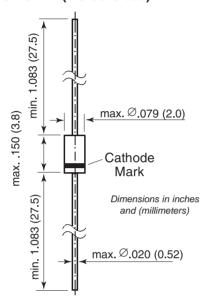
New Product

Vishay Semiconductors formerly General Semiconductor





DO-204AH (DO-35 Glass)



Features

- For general purpose applications
- These diodes feature very low turn-on voltage and fast switching. These devices are protected by a PN junction guard ring against excessive voltage, such as electrostatic discharges
- This diode is also available in the Mini-MELF case with type designations LL46

Mechanical Data

Case: DO-35 Glass Case Weight: approx. 0.13g

Packaging Codes/Options:

D7/10K per 13" reel (52mm tape), 20K/box D8/10K per Ammo tape (52mm tape), 20K/box

Maximum Ratings & Thermal Characteristics Ratings at 25°C ambient temperature unless otherwise specified.

Parameter	Symbol	Value	Unit
Repetitive Peak Reverse Voltage	VRRM	40	V
Forward Continuous Current at T _{amb} = 25°C	lF	350 ⁽¹⁾	mA
Repetitive Peak Forward Current at $t_p < 1s$, $\delta < 0.5$, $T_{amb} = 25^{\circ}C$	IFRM	1.0 ⁽¹⁾	А
Surge Forward Current at t _p < 10 ms, T _{amb} = 25°C	IFSM	7.5 ⁽¹⁾	А
Power Dissipation ⁽¹⁾ at T _{amb} = 65°C	Ptot	330 ⁽¹⁾	mW
Thermal Resistance Juntion to Ambient Air	R _θ JA	300 ⁽¹⁾	°C/W
Junction Temperature	Tj	125	°C
Ambient Operating Temperature Range	Tamb	-65 to +125	°C
Storage Temperature Range	Ts	-65 to +150	°C

Note: (1) Valid provided that leads at a distance of 4mm from case are kept at ambient temperature

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Electrical Characteristics Ratings at 25°C ambient temperature unless otherwise specified.

Parameter	Symbol	Min.	Тур.	Max.	Unit
Reverse Breakdown Voltage tested with 100µA Pulses	V _{(BR)R}	40	_	-	V
Forward Voltage Pulse Test $t_p < 300\mu s$, $\delta < 2\%$ at $I_F = 0.1 mA$ at $I_F = 1.0 mA$ at $I_F = 10 mA$ at $I_F = 50 mA$ at $I_F = 500 mA$ at $I_F = 500 mA$ at $I_F = 500 mA$	VF	- - - - -	- - - - -	0.25 0.30 0.40 0.50 0.75 0.90	V
Leakage Current Pulse Test $t_p < 300\mu s$, $\delta < 2\%$ at $V_R = 10V$ at $V_R = 10V$, $T_J = 60^{\circ}C$ at $V_R = 20V$ at $V_R = 20V$, $T_J = 60^{\circ}C$ at $V_R = 40V$ at $V_R = 40V$, $V_R = 40V$	lR	- - - - -	- - - - -	2 15 5 25 25 50	μΑ
Capacitance at V _R = 1V, f = 1MHz	Ctot	_	12	_	pF

Note: (1) Valid provided that leads at a distance of 4mm from case are kept at ambient temperature (DO-35)

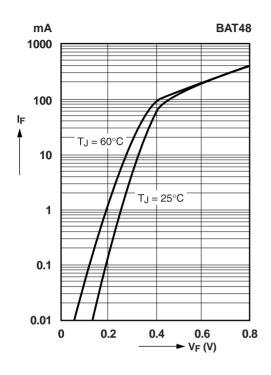
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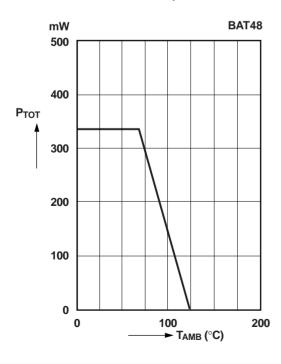
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Ratings and Characteristic Curves (TA = 25°C unless otherwise noted)

Forward Characteristics



Admissible Power Dissipation vs. Ambient Temperature



Typical Reverse Characteristics

